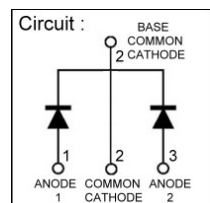
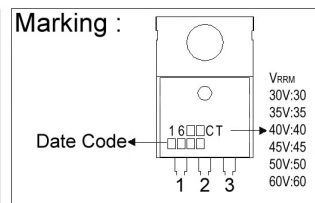
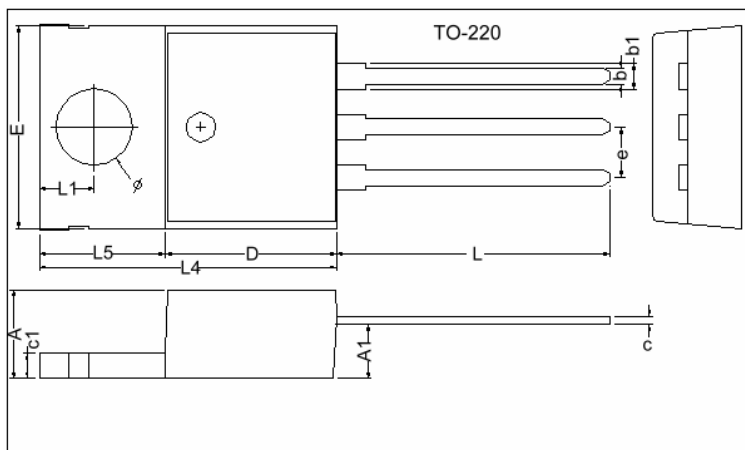


GESBL1630CT~1660CT**SCHOTTKY BARRIER RECTIFIERS****REVERSE VOLTAGE 30V TO 60V, CURRENT 16A****Description**

The GESBL1630CT~1660CT are designed for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.

Features

- Guard ring for transient protection
- Low power loss, high efficiency
- High current capability, low V_F
- High surge capacity

Package Dimensions

REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	4.40	4.80	c1	1.25	1.45
b	0.76	1.00	b1	1.17	1.47
c	0.36	0.50	L	13.25	14.25
D	8.60	9.00	e	2.54 REF.	
E	9.80	10.4	L1	2.60	2.89
L4	14.7	15.3	Ø	3.71	3.96
L5	6.20	6.60	A1	2.60	2.80

Maximum Ratings and Electrical Characteristics at $T_a=25^\circ\text{C}$ unless otherwise specified.

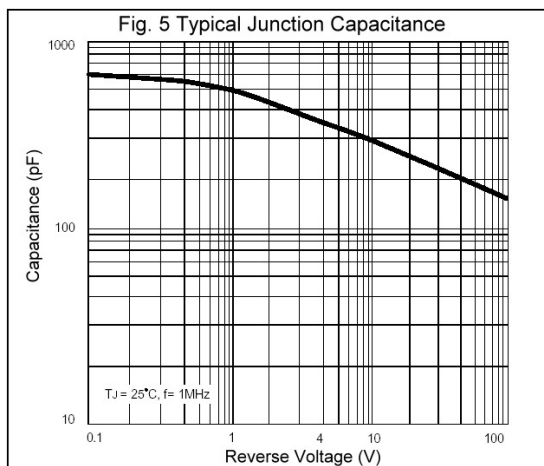
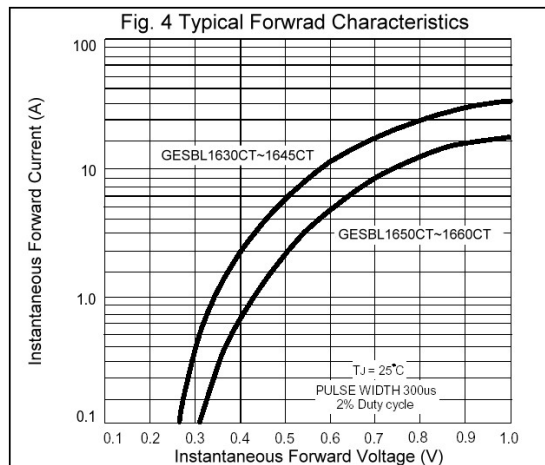
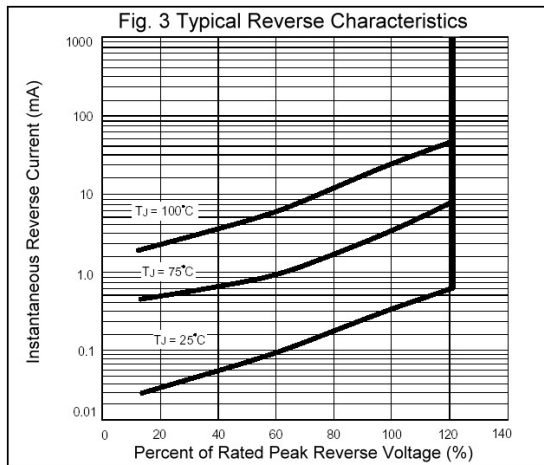
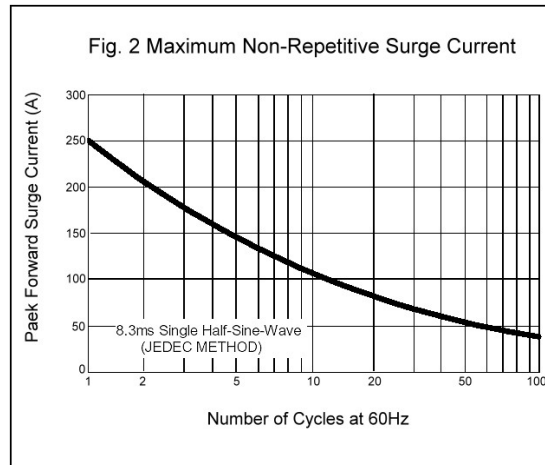
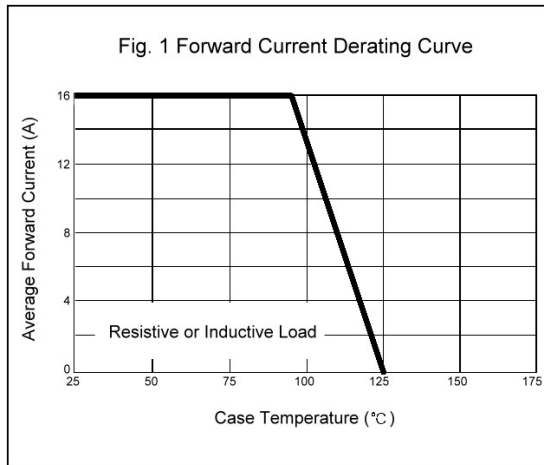
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%

Parameters	Symbol	Ratings						Unit
		GESBL 1630CT	GESBL 1635CT	GESBL 1640CT	GESBL 1645CT	GESBL 1650CT	GESBL 1660CT	V
Max. Recurrent Peak Reverse Voltage	V_{RRM}	30	35	40	45	50	60	V
Max. RMS Voltage	V_{RMS}	21	24.5	28	31.5	35	42	V
Max. DC Blocking Voltage	V_{DC}	30	35	40	45	50	60	V
Max. Average Forward Rectified Current (See Fig.1) @ $T_C=95^{\circ}C$	$I_{(AV)}$	16						A
Peak Surge Forward Current 8.3ms single half sine-wave superimposed on rated load (JEDEC METHOD)	I_{FSM}	250						A
Max. Forward Voltage @ 8A (Note 1)	V_F	0.55				0.7		V
Max. DC Reverse Current @ $T_J=25^{\circ}C$ At Rated DC Blocking Voltage @ $T_J=100^{\circ}C$	I_R	0.5 50						mA
Typical Thermal Resistance (Note 2)	$R_{\theta JC}$	2.5						$^{\circ}C/W$
Operating Temperature Range	T_j	-55 ~ +125						$^{\circ}C$
Storage Temperature Range	T_{stg}	-55 ~ +150						$^{\circ}C$

Notes: 1. 300us Pulse Width, 2% Duty Cycle.

2. Thermal Resistance Junction to Case.

Characteristics Curve



Important Notice:

- All rights are reserved. Reproduction in whole or in part is prohibited without the prior written approval of GTM.
- GTM reserves the right to make changes to its products without notice.
- GTM semiconductor products are not warranted to be suitable for use in life-support Applications, or systems.
- GTM assumes no liability for any consequence of customer product design, infringement of patents, or application assistance.

Head Office And Factory:

- Taiwan:** No. 17-1 Tatung Rd. Fu Kou Hsin-Chu Industrial Park, Hsin-Chu, Taiwan, R. O. C.
TEL : 886-3-597-7061 FAX : 886-3-597-9220, 597-0785
- China:** (201203) No.255, Jang-Jiang Tsai-Lueng RD. , Pu-Dung-Hsin District, Shang-Hai City, China
TEL : 86-21-5895-7671 ~ 4 FAX : 86-21-38950165